NSN 5962-01-330-9316

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-330-9316 **Body Length:** Between 0.442 inches and 0.460 inches **Body Width:** Between 0.442 inches and 0.460 inches **Body Height:** Between 0.060 inches and 0.100 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** Tactical air operations module an/tyq-2 (v) 1 **Features Provided:** Electrostatic sensitive and monolithic and bipolar and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Leadless flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** C-4 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source **Memory Device Type:** Rom **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 28 leadless Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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